



Description

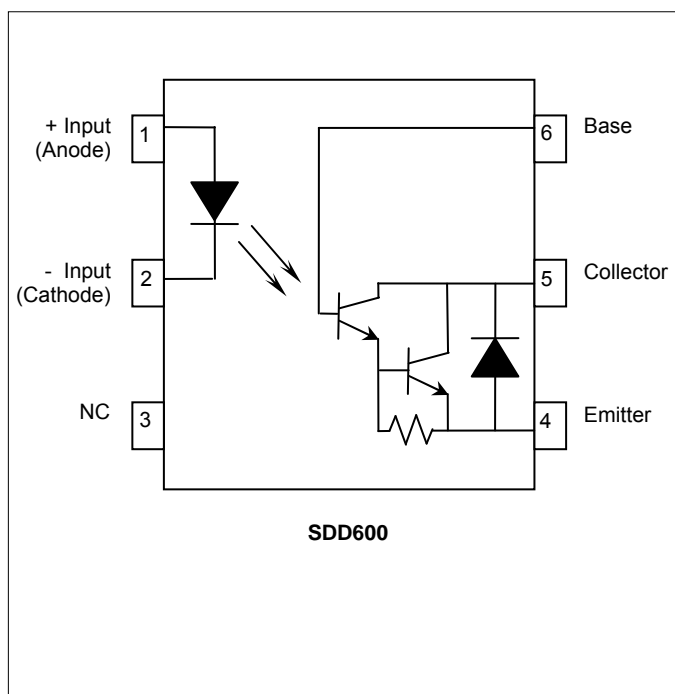
The SDD600 consists of a high voltage photo-Darlington transistor optically coupled to a light emitting diode. Optical coupling between the input IR LED and output photo-Darlington allows for high isolation levels while maintaining low-level DC signal control capability. The SDD600 provides an optically isolated method of controlling many interface applications such as telecommunications, industrial control, and instrumentation circuitry

The SDD600 comes standard in a miniature 6 pin DIP package.

Applications

- Office Automation Equipment
- System Appliances, Measuring Instruments
- Computer Terminals, PLCs
- Telecom / Datacom
- Home Appliances
- Digital Logic Inputs
- Fax / Modems
- Power Supplies

Schematic Diagram



Features

- High Load Voltage ($V_{CEO} = 300V \text{ MIN}$)
- High Current Transfer Ratio (CTR: 600-9000%)
- Low input power consumption
- High stability
- High Isolation Voltage (5000V_{RMS})
- Long Life / High Reliability
- RoHS / Pb-Free / REACH Compliant

Agency Approvals

UL: File # E201932
C-UL: File # E201932
VDE: License # 40011227

Absolute Maximum Ratings

The values indicated are absolute stress ratings. Functional operation of the device is not implied at these or any conditions in excess of those defined in electrical characteristics section of this document. Exposure to absolute Maximum Ratings may cause permanent damage to the device and may adversely affect reliability.

Storage Temperature-55 to +125°C
Operating Temperature-40 to +100°C
Continuous Input Current50mA
Transient Input Current500mA
Reverse Input Control Voltage6V
Input Power Dissipation40mW
Total Power Dissipation200mW
Solder Temperature – Wave (10sec)260°C
Solder Temperature – IR Reflow (10sec)260°C

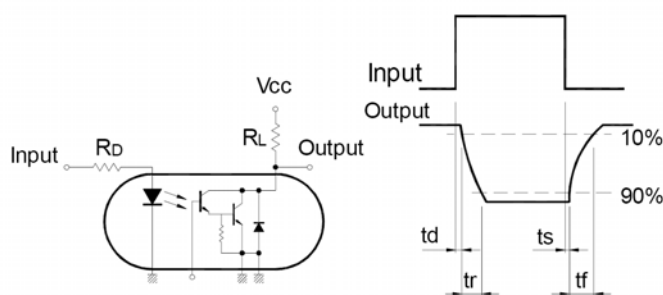
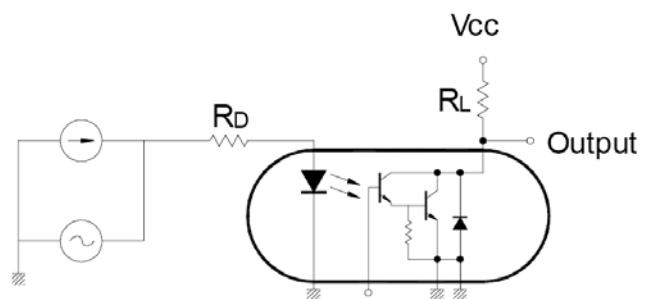
Ordering Information

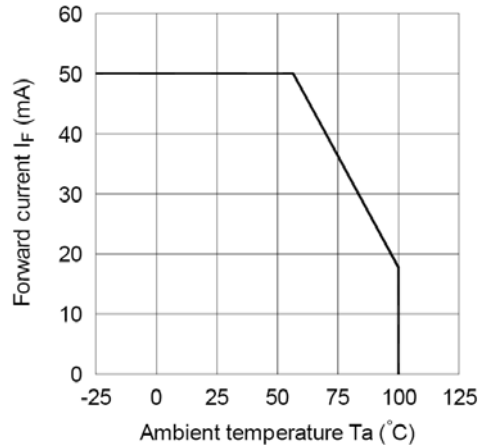
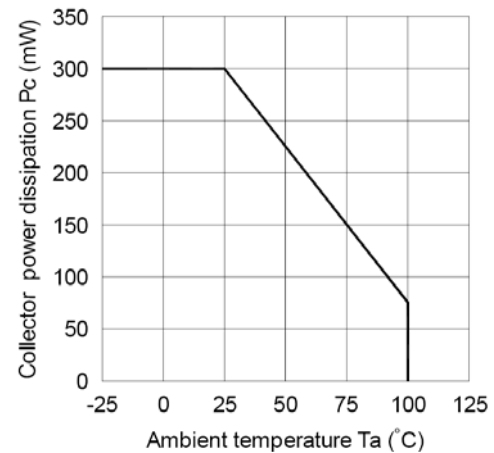
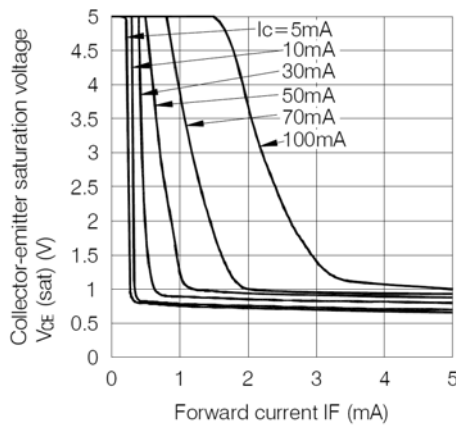
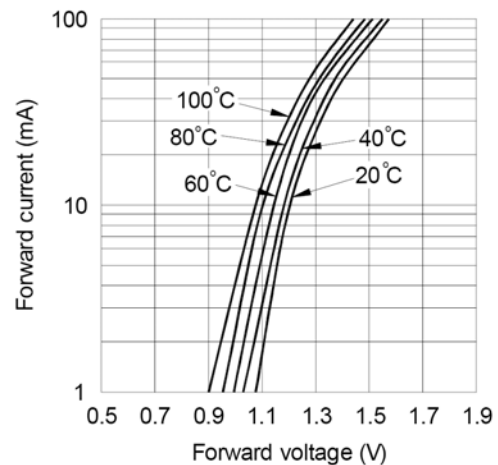
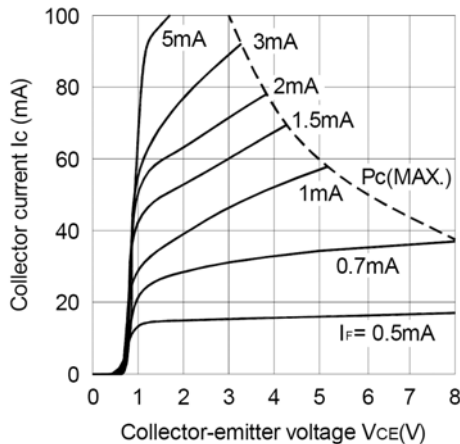
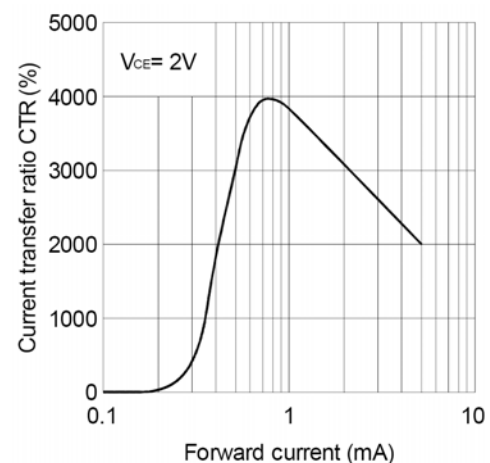
Part Number	Description
SDD600	6 pin DIP, (65/Tube)
SDD600-H	0.40" (10.16mm) Lead Spacing (VDE0884)
SDD600-S	6 pin SMD, (65/Tube)
SDD600-STR	6 pin SMD, Tape and Reel (2000/Reel)

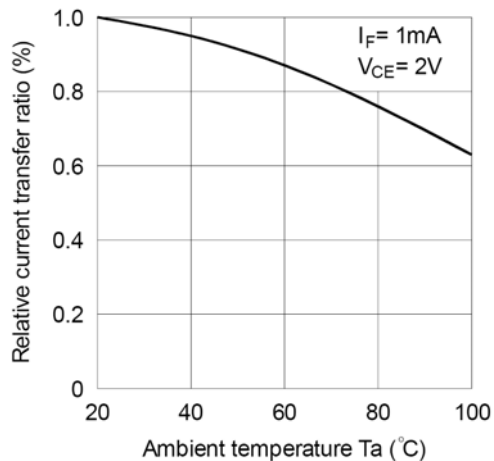
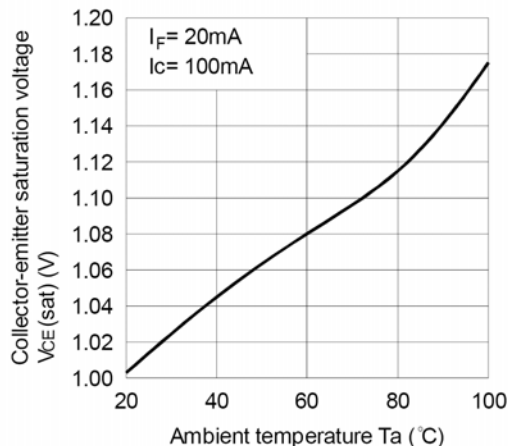
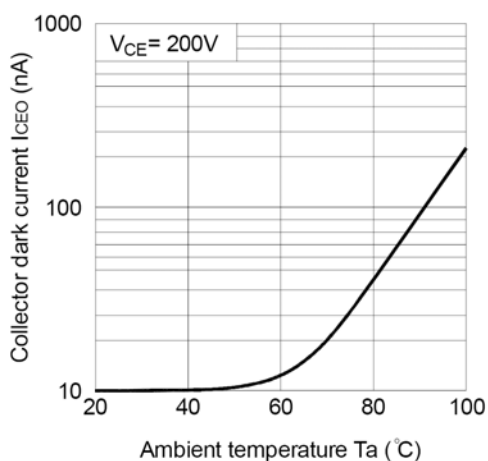
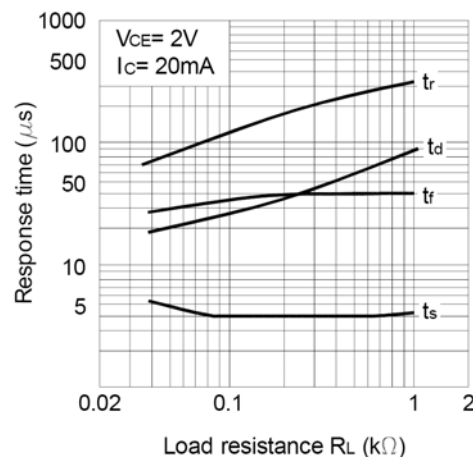
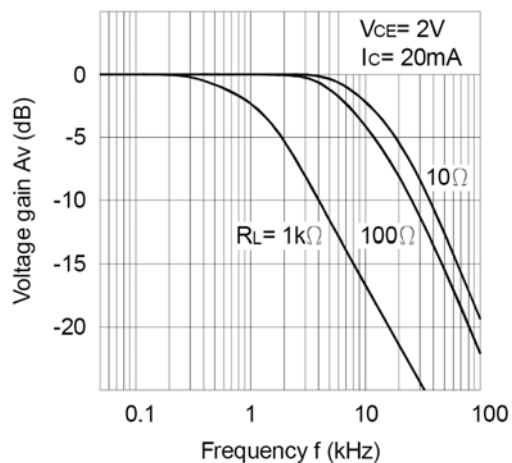
NOTE: Suffixes listed above are not included in marking on device for part number identification

Electrical Characteristics, $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Input Specifications						
LED Forward Voltage	V_F	-	1.2	1.4	V	$I_F = 10\text{mA}$
LED Reverse Voltage	BV_R	5	-	-	V	$I_R = 10\mu\text{A}$
Terminal Capacitance	C_t	-	30	250	pF	$V=0, f=1\text{KHz}$
Reverse Current	I_R	-	-	10	μA	$V_R=4\text{V}$
Output Specifications						
Collector-Emitter Voltage	V_{CEO}	300	-	-	V	$I_C=10\mu\text{A}$
Emitter-Collector Voltage	V_{COE}	0.1	-	-	V	$I_E=10\mu\text{A}$
Collector Dark Current	I_{CEO}	-	-	1	μA	$V_{CE}=200\text{V}, I_F=0\text{mA}$
Floating Capacitance	C_f	-	0.6	1.0	pF	$V=0, f=1\text{MHz}$
Cut-Off Frequency	f_c	1	7	-	kHz	$V_{CE}=2\text{V}, I_C=20\text{mA}, R_L=100\Omega, -3\text{dB}$
Saturation Voltage	$V_{CE(sat)}$	-	-	1.2	V	$I_F=20\text{mA}, I_C=100\text{mA}$
Coupled Specifications						
Rise Time	T_R	-	100	300	μs	$I_C=20\text{mA}, V_{CC}=2\text{V}, R_L=100\Omega$
Fall Time	T_F	-	20	100	μs	$I_C=20\text{mA}, V_{CC}=2\text{V}, R_L=100\Omega$
Current Transfer Ratio	CTR	1000	4000	15000	%	$I_F=1\text{mA}, V_{CE}=2\text{V}$
Isolation Specifications						
Isolation Voltage	V_{ISO}	5000	-	-	V_{RMS}	$RH \leq 50\%, t=1\text{min}$
Input-Output Resistance	R_{I-O}	-	10^{12}	-	Ω	$V_{I-O} = 500V_{DC}$

Test Circuit: Response Time

Test Circuit: Frequency Response


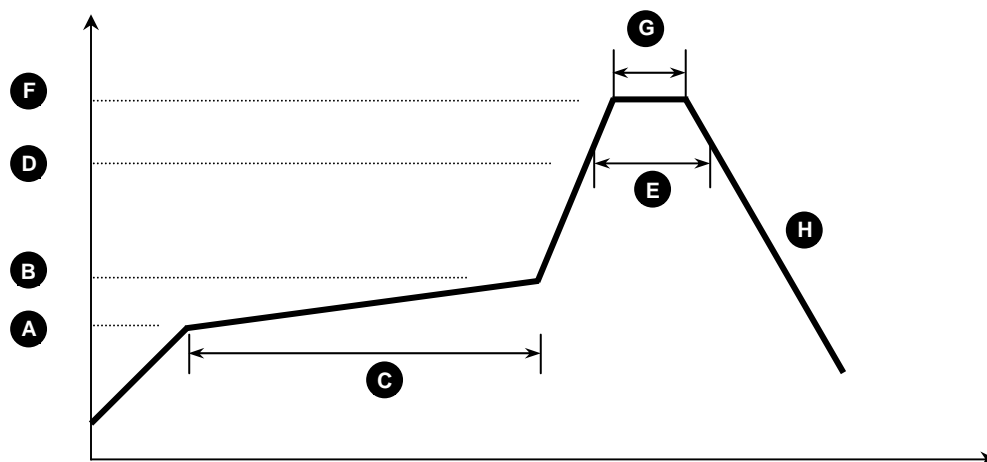
SDD600 Performance & Characteristics Plots, $T_A = 25^\circ\text{C}$ (unless otherwise specified)
Figure 1: Forward Current (I_F) vs. Temperature ($^\circ\text{C}$)

Figure 2: Collector Power Dissipation (P_C) vs. Temperature ($^\circ\text{C}$)

Figure 3: Collector-Emitter Saturation Voltage ($V_{CE(SAT)}$) vs. Forward Current (I_F)

Figure 4: Forward Current (I_F) vs. Forward Voltage (V_F)

Figure 5: Collector Current (I_C) vs. Collector-Emitter Voltage (V_{CE})

Figure 6: Current Transfer Ratio (CTR) vs. Forward Current (I_F)


SDD600 Performance & Characteristics Plots, $T_A = 25^\circ\text{C}$ (unless otherwise specified)
Figure 7: Relative CTR (%) vs. Temperature ($^\circ\text{C}$)

Figure 8: Collector-Emitter Saturation Voltage ($V_{CE(\text{SAT})}$) vs. Temperature ($^\circ\text{C}$)

Figure 9: Collector Dark Current (I_{CEO}) vs. Temperature ($^\circ\text{C}$)

Figure 10: Response Times vs. Load Resistance (R_L)

Figure 11: Frequency Response Characteristics


SDD600 Solder Reflow Temperature Profile Recommendations

(1) Infrared Reflow:

Refer to the following figure as an example of an optimal temperature profile for single occurrence infrared reflow. Soldering process should not exceed temperature or time limits expressed herein. Surface temperature of device package should not exceed 250°C:



Process Step	Description	Parameter
A	Preheat Start Temperature (°C)	150°C
B	Preheat Finish Temperature (°C)	180°C
C	Preheat Time (s)	90 - 120s
D	Melting Temperature (°C)	230°C
E	Time above Melting Temperature (s)	30s
F	Peak Temperature, at Terminal (°C)	260°C
G	Dwell Time at Peak Temperature (s)	10s
H	Cool-down (°C/s)	<6°C/s

(2) Wave Solder:

Maximum Temperature: 260°C (at terminal)
Maximum Time: 10s
Pre-heating: 100 - 150°C (30 - 90s)
Single Occurrence

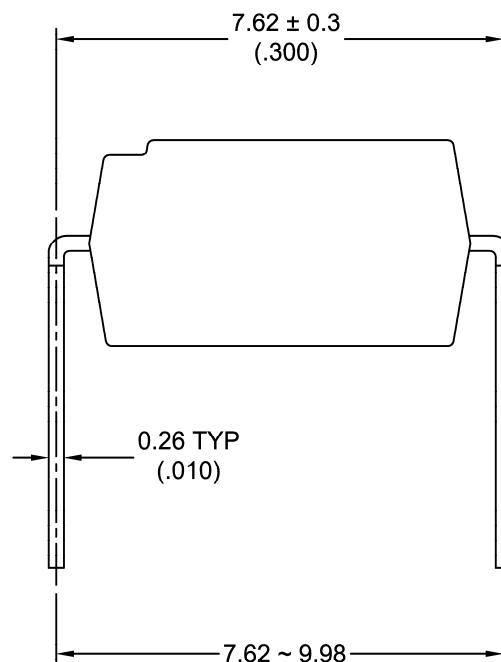
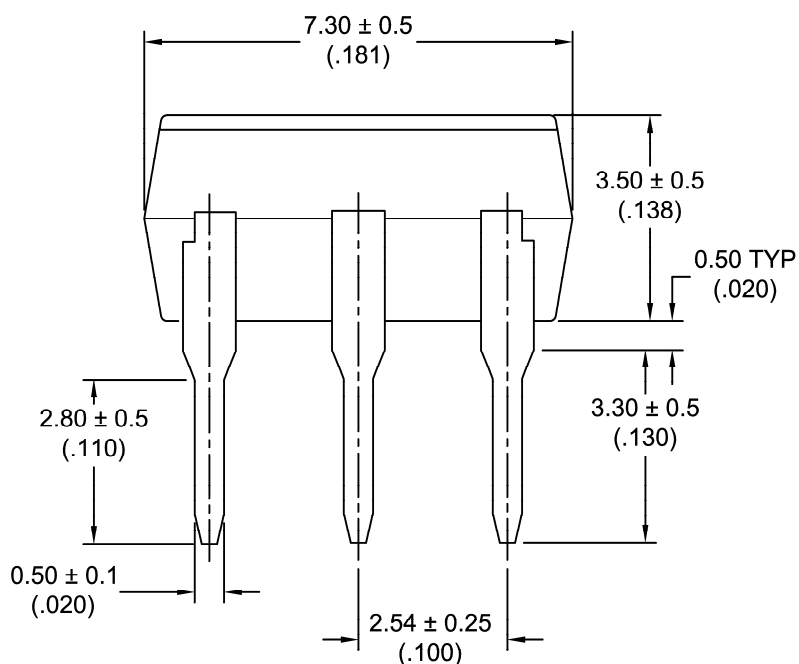
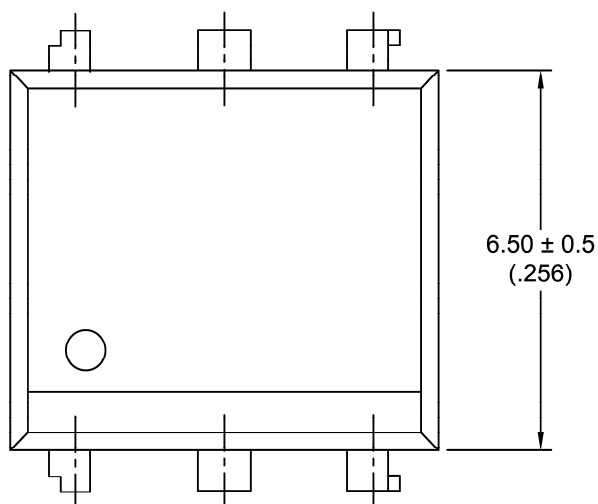
(3) Hand Solder:

Maximum Temperature: 350°C (at tip of soldering iron)
Maximum Time: 3s
Single Occurrence

SDD600 Package Dimensions

6 PIN DIP Package

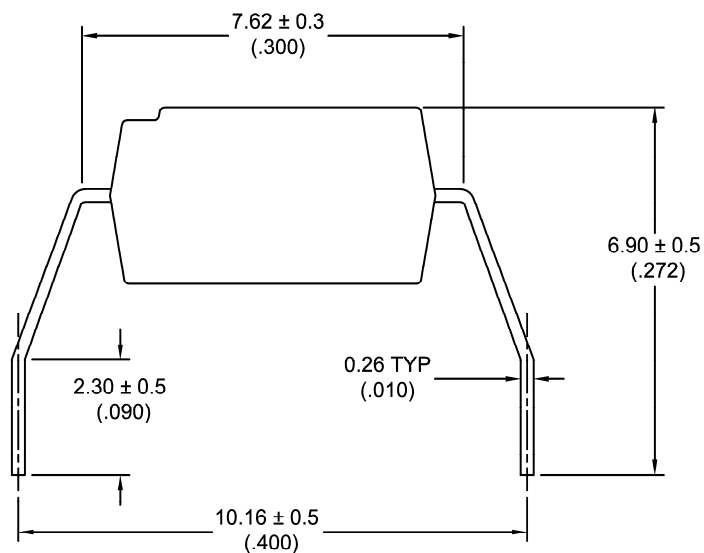
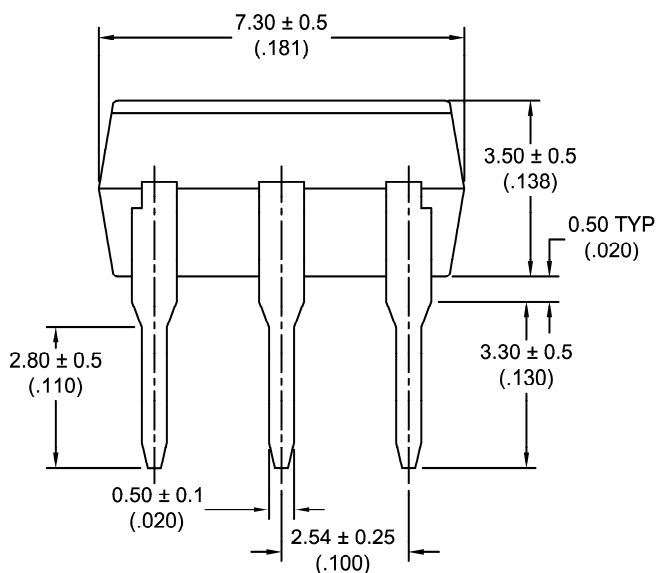
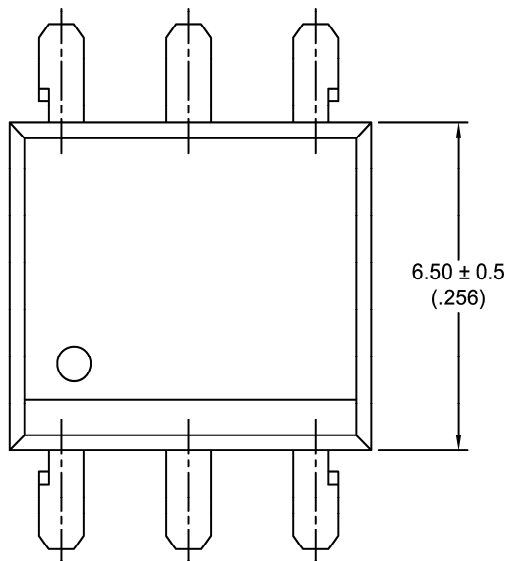
Note: All dimensions in millimeters [mm] with inches in parenthesis ()



SDD600 Package Dimensions

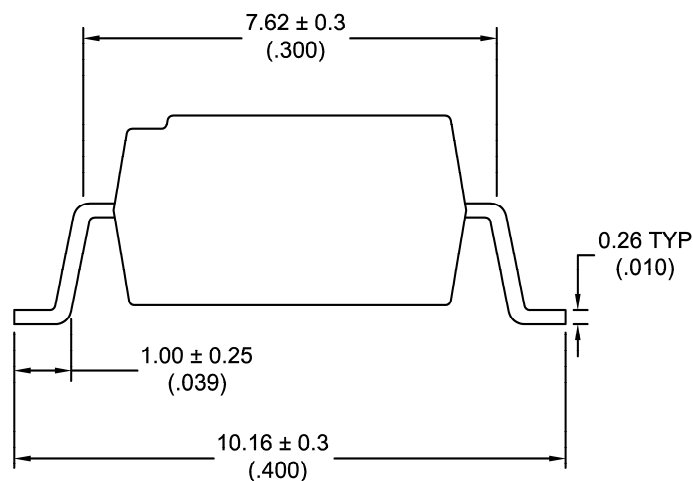
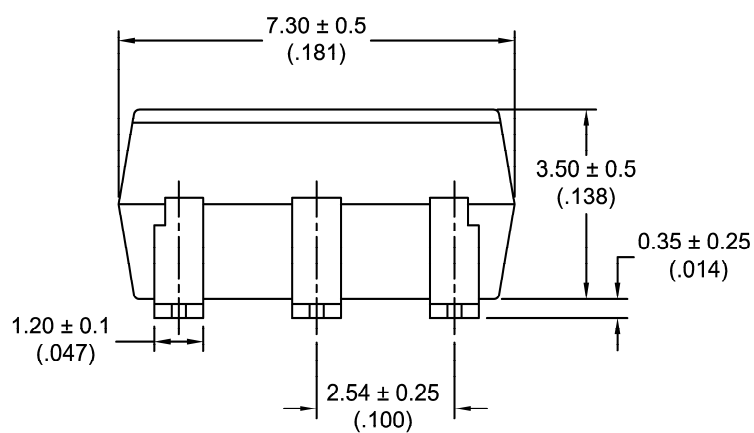
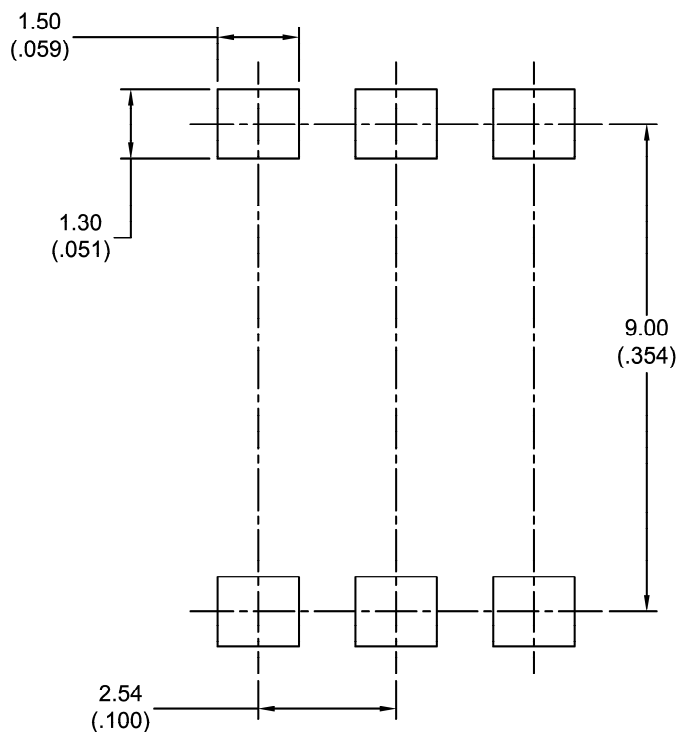
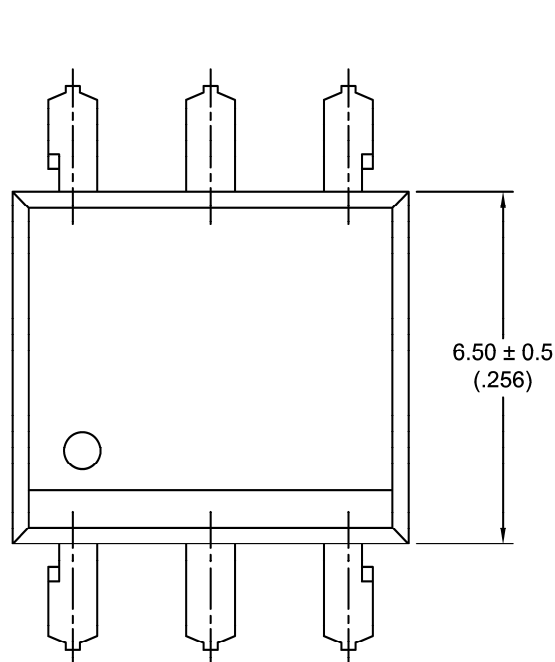
6 PIN WIDE Lead Space Package (-H)

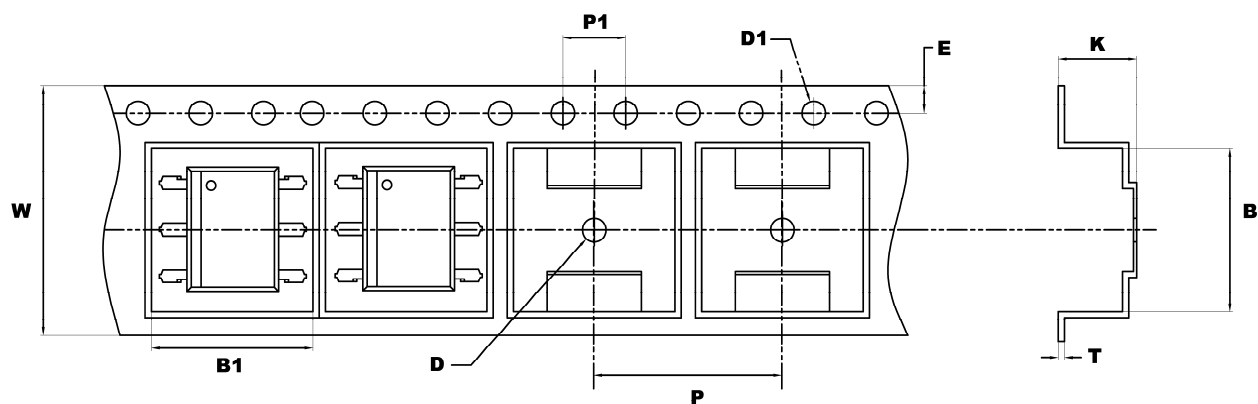
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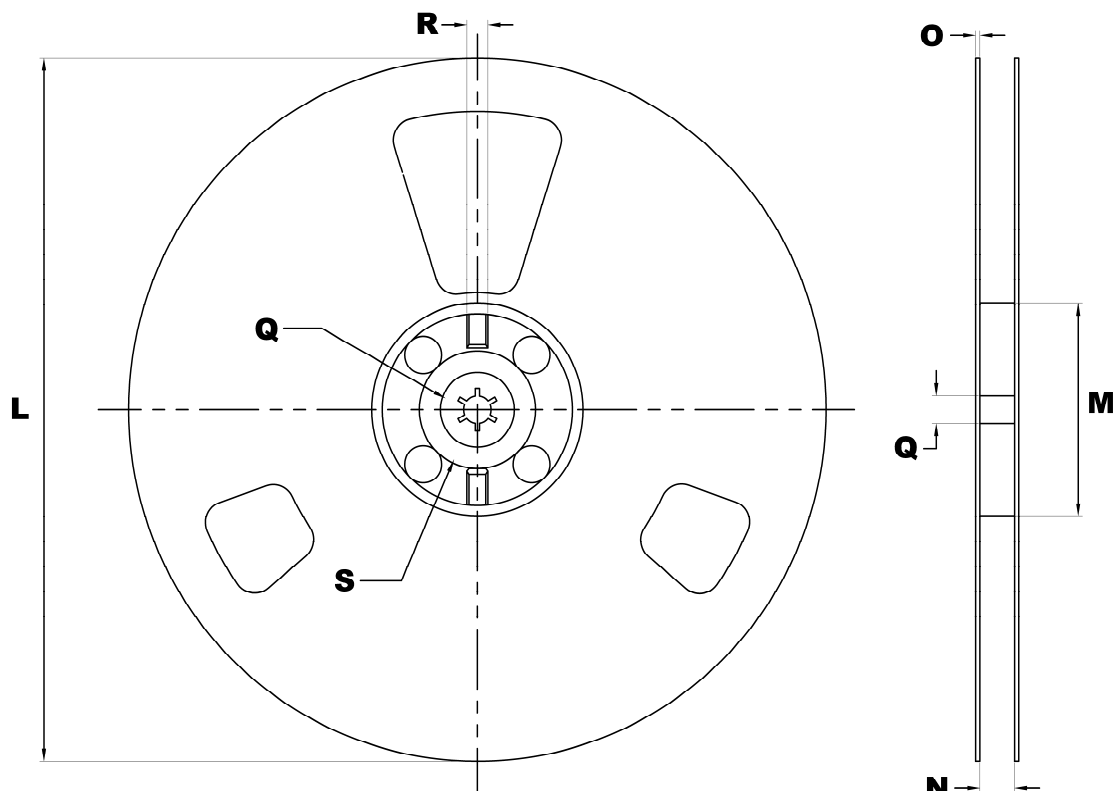
SDD600 Package Dimensions
6 PIN SMD Surface Mount Package (-S)

Note: All dimensions in millimeters [mm] with inches in parenthesis ()



SDD600 Packaging Specifications
Tape & Reel Specifications (T&R)
Note: All dimensions in millimeters [mm]


B	B1	D	D1	E	K	P	P1	T	W
7.70±0.1	10.46±0.1	ø1.60±0.1	ø1.55±0.05	1.75±0.1	4.25±0.1	12.0±0.1	4.00±0.1	0.3±0.05	16±0.3



L	M	N	O	Q	R	S
330±2	101.6±1	16.4±0.2	2.0±0.2	R13±0.5	1.50±0.5	R10±1

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